BAT54STB DIODE

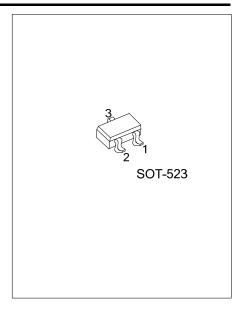
SCHOTTKY BARRIER (DUAL) DIODES

■ DESCRIPTION

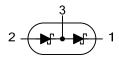
Planar Schottky barrier diodes are encapsulated in the SOT-523 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

■ FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package



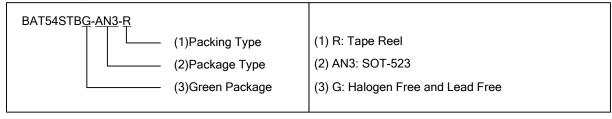
■ SYMBOL



■ ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Daakina	
		1	2	3	Packing	
BAT54STBG-AN3-R	SOT-523	K1	A2	K2A1	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



MARKING



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BAT54STB DIODE

■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT			
PER DIODE						
Continuous Reverse Voltage	V_R	30	V			
Continuous Forward Current	l _F	200	mA			
Repetitive Peak Forward Current (t _P <1s, δ≤0.5)	I _{FRM}	300	mA			
Non-repetitive Peak Forward Current (t _P <10ms)	I _{FSM}	600	mA			
Junction Temperature	T_J	+125	°C			
Storage Temperature	T _{STG}	-60 ~ +150	°C			
PER DEVICE						
Power Dissipation (T _A ≤25°C)	P _D	230	mW			

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	500	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	V _F	$I_F = 0.1 \text{mA}$			240	mV
		$I_F = 1mA$			320	mV
		$I_F = 10mA$			400	mV
		$I_F = 30mA$			500	mV
		I _F = 100mA			800	mV
Reverse Current (See Fig.2)	I _R	V _R = 25V			2	μA
Reverse Recovery Time (see Fig.4)	t _{rr}	When switched from I _F =10mA				
		to $I_R = 10 \text{mA}, R_L = 100 \Omega$			5	ns
		measured at I _R = 1mA				
Diode Capacitance (see Fig.3)	C_D	$f = 1 \text{ MHz}, V_R = 1V;$			10	рF

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■ TYPICAL CHARACTERISTICS

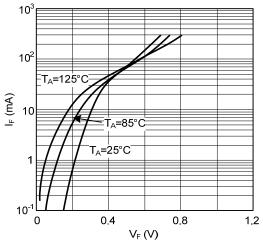


Fig.1 Forward current as a function of forward voltage; typical values.

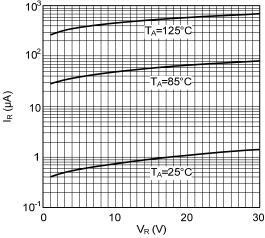


Fig.2 Reverse current as a function of reverse voltage; typical values.

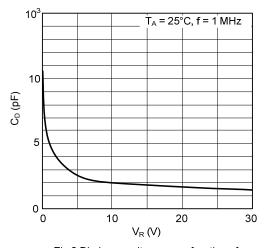


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

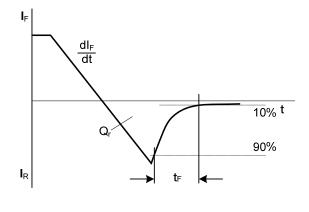


Fig.4 Reverse recovery definitions

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